Complementary Silicon Plastic Power Transistors

Designed for use in general purpose amplifier and switching applications. Compact TO-220 AB package.

Features

• Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating	Symbol	29 30	29A 30A	29B 30B	29C 30C	Unit
Collector – Emitter Voltage	V _{CEO}	40	60	80	100	Vdc
Collector - Base Voltage	V _{CB}	40	60	80	100	Vdc
Emitter – Base Voltage	V _{EB}	5.0			Vdc	
Collector Current - Continuous - Peak	lc	1.0 3.0			Adc	
Base Current	I _B	0.4			Adc	
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	30 0.24			W W/°C	
Total Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	2.0 0.016			W W/°C	
Unclamped Inductive Load Energy (Note 1)	Е	32			mJ	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150			°C	

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	62.5	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	4.167	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. This rating based on testing with L_C = 20 mH, R_{BE} = 100 Ω , V_{CC} = 10 V, I_C = 1.8 A, P.R.F = 10 Hz

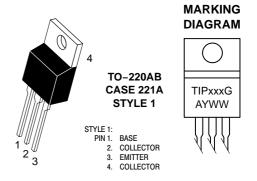
*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



ON Semiconductor®

http://onsemi.com

1 AMPERE POWER TRANSISTORS COMPLEMENTARY SILICON 40, 60, 80, 100 VOLTS, 80 WATTS



TIPxxx = Device Code:

29, 29A, 29B, 29C 30, 30A, 30B, 30C

A = Assembly Location

Y = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

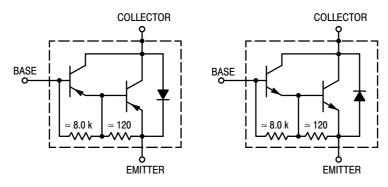


Figure 1. Darlington Circuit Schematic

ORDERING INFORMATION

Device	Package	Shipping	
TIP29	TO-220	50 Units / Rail	
TIP29G	TO-220 (Pb-Free)	50 Units / Rail	
TIP29A	TO-220	50 Units / Rail	
TIP29AG	TO-220 (Pb-Free)	50 Units / Rail	
TIP29B	TO-220	50 Units / Rail	
TIP29BG	TO-220 (Pb-Free)	50 Units / Rail	
TIP29C	TO-220	50 Units / Rail	
TIP29CG	TO-220 (Pb-Free)	50 Units / Rail	
TIP30	TO-220	50 Units / Rail	
TIP30G	TO-220 (Pb-Free)	50 Units / Rail	
TIP30A	TO-220	50 Units / Rail	
TIP30AG	TO-220 (Pb-Free)	50 Units / Rail	
TIP30B	TO-220	50 Units / Rail	
TIP30BG	TO-220 (Pb-Free)	50 Units / Rail	
TIP30C	TO-220	50 Units / Rail	
TIP30CG	TO-220 (Pb-Free)	50 Units / Rail	

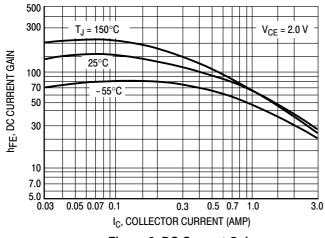
ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	•	•	•	
Collector–Emitter Sustaining Voltage (I _C = 30 mAdc, I _B = 0) (Note 2) TIP29, TIP30 TIP29A, TIP30B TIP29B, TIP30B TIP29C, TIP30C	k	40 60 80 100	- - - -	Vdc
		- -	0.3 0.3	mAdc
	¥ \$	- - - -	200 200 200 200	μAdc
Emitter Cutoff Current (V _{BE} = 5.0 Vdc, I _C = 0)	I _{EBO}	_	1.0	mAdc
ON CHARACTERISTICS (Note 2)				•
DC Current Gain ($I_C = 0.2$ Adc, $V_{CE} = 4.0$ Vdc) ($I_C = 1.0$ Adc, $V_{CE} = 4.0$ Vdc)	h _{FE}	40 15	- 75	-
Collector–Emitter Saturation Voltage (I _C = 1.0 Adc, I _B = 125 mAdc)	V _{CE(sat)}	_	0.7	Vdc
Base–Emitter On Voltage (I _C = 1.0 Adc, V _{CE} = 4.0 Vdc)	V _{BE(on)}	_	1.3	Vdc
DYNAMIC CHARACTERISTICS				
Current–Gain – Bandwidth Product (Note 3) (I_C = 200 mAdc, V_{CE} = 10 Vdc, f_{test} = 1.0 MHz)	f _T	3.0	-	MHz
Small-Signal Current Gain (I _C = 0.2 Adc, V _{CE} = 10 Vdc, f = 1.0 kHz)	h _{fe}	20	-	_

^{2.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0% 3. $f_T = |h_{fe}| \bullet f_{test}$

3.0

2.0

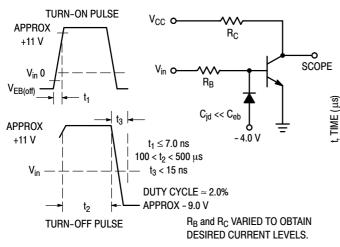


 $I_C/I_B=10$ $t_s' = t_s - 1/8 t_f$ 1.0 $T_J = 25^{\circ}C$ $t_f @ V_{CC} = 30 V$ 0.7 0.5 t, TIME (µs) 0.3 $t_f @ V_{CC} = 10 V$ 0.2 0.1 0.07 0.05 0.03 0.05 0.07 0.1 0.3 0.2 0.7 1.0 2.0 3.0 IC, COLLECTOR CURRENT (AMP)

 $I_{B1} = I_{B2}$

Figure 2. DC Current Gain

Figure 3. Turn-Off Time



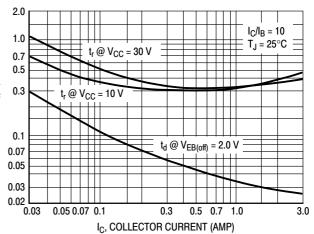


Figure 4. Switching Time Equivalent Circuit

Figure 5. Turn-On Time

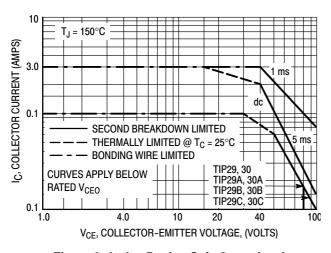


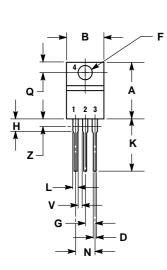
Figure 6. Active Region Safe Operating Area

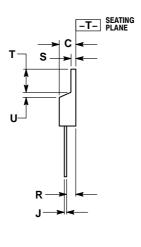
There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 6 is based on $T_{J(pk)} = 150^{\circ}C$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ}C$. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AG**





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
С	0.160	0.190	4.07	4.82	
D	0.025	0.036	0.64	0.91	
F	0.142	0.161	3.61	4.09	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.161	2.80	4.10	
J	0.014	0.025	0.36	0.64	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
Т	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
٧	0.045		1.15		
Z		0.080		2.04	

PIN 1 BASE

COLLECTOR 2.

EMITTER COLLECTOR

ON Semiconductor and 🕠 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice on semiconductor and water legistered readerlands of semiconductor Components industries, Ltc (SCILLC) solicit esserves the inject that changes without further holice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications. intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada

Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada

Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative